# Compact discharge based EUV source for metrology and inspection

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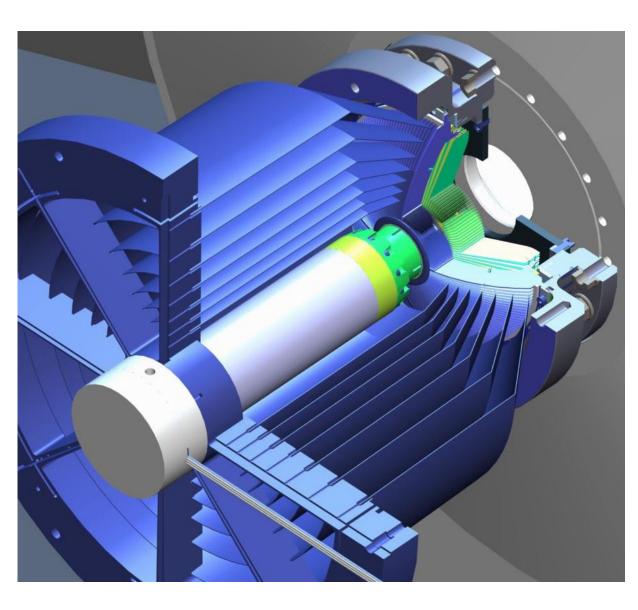
#### FS5420: 20 W EUV Source



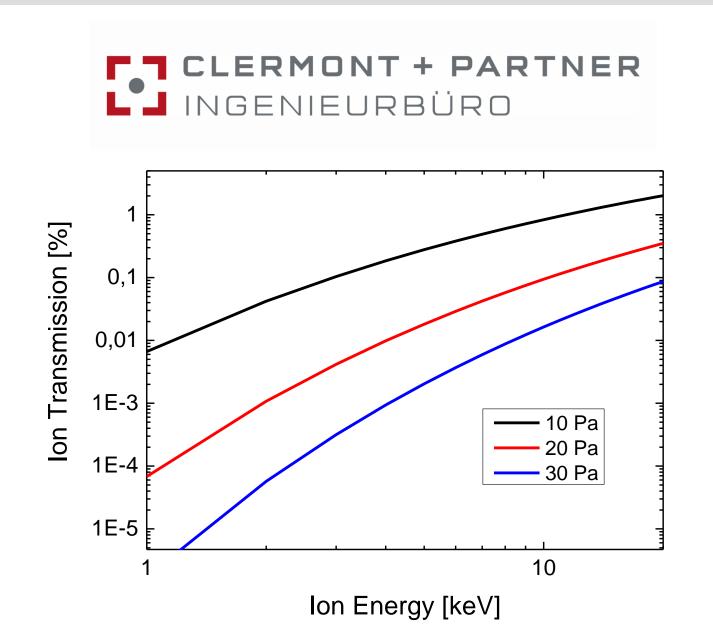
Discharge source FS5420 (source, control unit, chillers)

- Max. input power: 15 kW
- Max. pulse energy: 10 J
- Max. repetition rate : 2.5 kHz
- IF-intensity ~40 mW/mm² with matched collector
- Typical plasma length: 3-5 mm
- Typical emission diameter at 13.5 nm: < 300 μm (FWHM)
- Accessible collection angle: > 80°

## Source Collector Module with Foiltrap



FS5420 Source Collector Module with integrated foiltrap

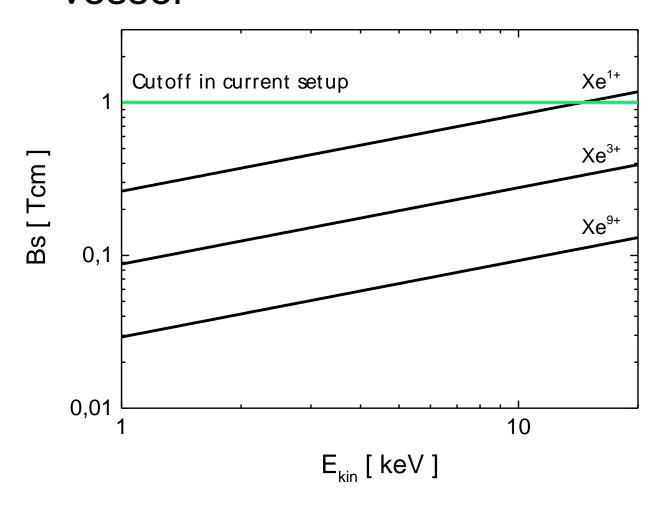


Monte Carlo simulation of foiltrap transmission propability of Xe-ions

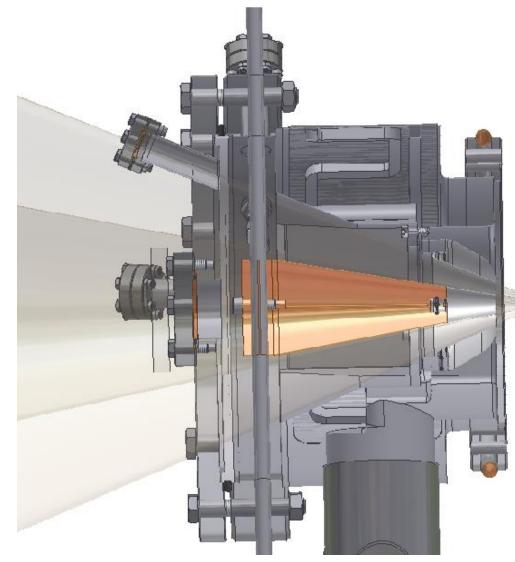
- Mitigation of fast lons in foiltrap in combination with buffer gas
- IF-intensity including foiltrap and gas transmission: **25 mW/mm²**

## Gas Flow / Magnetic Debris-Mitigation

- Accessible collection angle:
   23° (no central stop)
   23°-45° (central stop)
- Magnetic counter pressure (B²/2μ₀) for slow expanding plasma
- Deflection of fast ions in B-Field
- Mitigation of electrode vapor by purge gas flow towards the source
- Up to 200–400 mT in shielded vessel



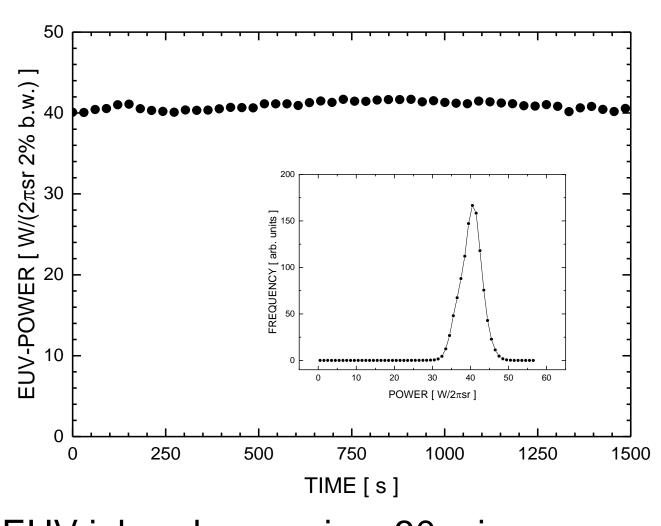




Magnetic debris-mitigation system with central-stop (top)

B-s for 20° deflection of Xe-ions (left)

#### Performance at 40 W



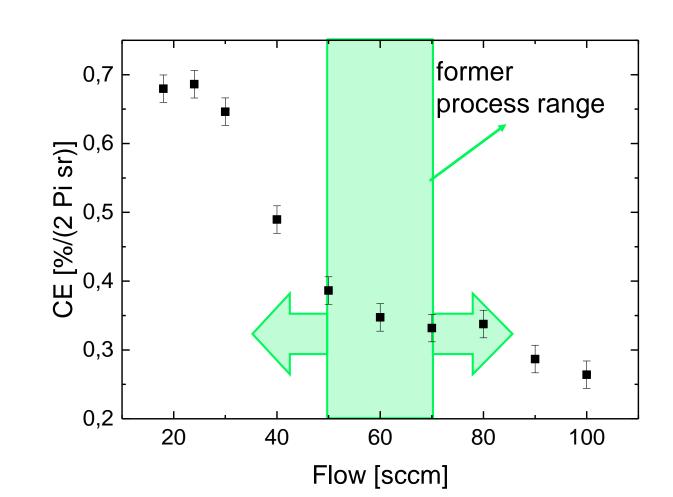
EUV inband power in a 30 min run

Typical xenon emission spectrum

Standard deviation (pulse-to-pulse) :  $\sigma$  = 6.8 %

### Efficiency optimization

- Extended range of operation for Xe- flow due to advanced triggering
- Higher tolerance towards electrode erosion (tested electrodes had >150 Mshot)
- Higher conversion efficiency (~0.7 %) at lower gas flows achievable



Flow dependence of CE at 6 kW input power

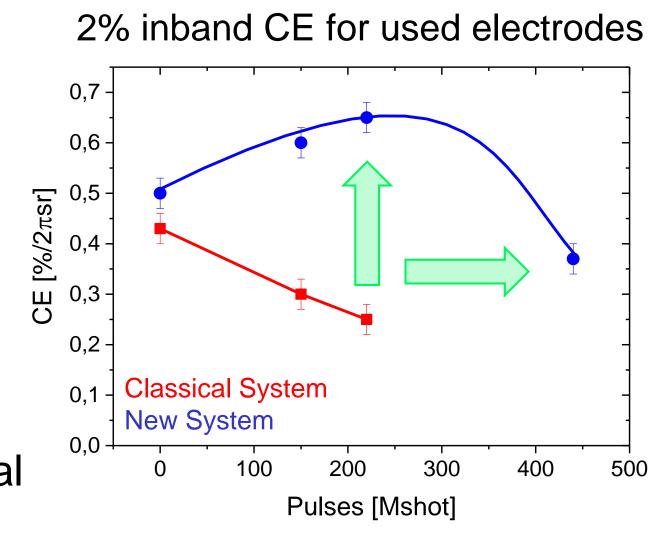
13.5 nm inband performance at 6 kW input:

EUV Power EUV Brigthness
 40 W/(2πsr) 12 W/(mm²sr)

# **Increasing Lifetime**

#### **Classical System:**

- Wear of IP (Intermediate Plate) is mainly determining the source performance
- Xe-flow increases with wear of IP
- Higher flow lead to lower CE and reduces the working range
- 100-250 Mshot maintenance interval



#### **New System:**

- Advanced triggering allows operation at lower Xe-flow with increase of CE at higher tolerance towards electrode erosion
- Expected electrode lifetimes of >1 Gshot

# Acknowledgements

Parts of this work have been supported by:

Supported by:

Federal Ministry
for Economic Affairs
and Energy

on the basis of a decision by the German Bundestag



